



IXFH80N65X2

Manufacturer Part Number:	IXFH80N65X2
Manufacturer/Brand:	IXYS Corporation
Part of Description:	MOSFET N-CH 650V 80A TO-247
Datasheets:	IXFH80N65X2.pdf
RoHs Status:	Lead free / RoHS Compliant
Stock Condition:	New original, 4560 pcs Stock Available.
Ship From:	Hong Kong
Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Image may be representation.
See specs for product details.

Specifications

Part Number	IXFH80N65X2
Manufacturer	IXYS Corporation
Description	MOSFET N-CH 650V 80A TO-247
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	4560 pcs Stock
Series	HiPerFET™
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	TO-247
Power Dissipation (Max)	890W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)
Rds On (Max) @ Id, Vgs	40 mOhm @ 40A, 10V
Vgs(th) (Max) @ Id	5.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	143nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	8245pF @ 25V
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Packaging	Tube

IXFH80N65X2 is New Original in Stock, Search IXFH80N65X2 Datasheets, PDF, Inventory at Y-IC.com Online, Order IXFH80N65X2 IXYS Corporation with warrantied and confidence.
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